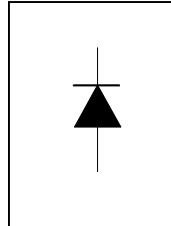


### FAST SOFT RECOVERY RECTIFIER DIODE



$$V_F < 1.2V @ 10A$$

$$t_{rr} = 50ns$$

$$V_{RRM} 200 \text{ to } 600V$$

#### Description/Features

The 10ETF..FP fast soft recovery *QUIETIR* rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

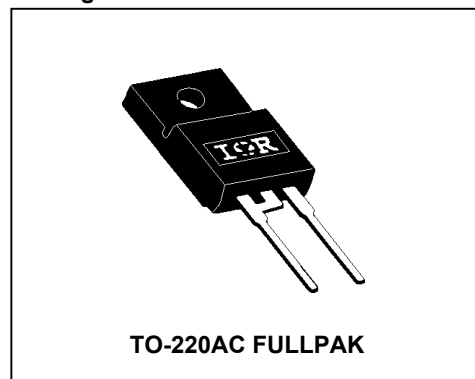
Typical applications are both:

- output rectification and freewheeling in inverters, choppers and converters
- and input rectifications where severe restrictions on conducted EMI should be met.

#### Major Ratings and Characteristics

Characteristics	10ETF..FP	Units
$I_{F(AV)}$ Sinusoidal waveform	10	A
$V_{RRM}$	200 to 600	V
$I_{FSM}$	150	A
$V_F$ @ 10A, $T_J = 25^\circ C$	1.2	V
$t_{rr}$ @ 1A, 100A/ $\mu s$	50	ns
$T_J$	-40 to 150	$^\circ C$

#### Package Outline



# 10ETF..FP QUIETIR Series

Bulletin I2163 04/02

International  
**IR** Rectifier

## Voltage Ratings

Part Number	$V_{RRM}$ , maximum peak reverse voltage V	$V_{RSM}$ , maximum non repetitive peak reverse voltage V	$I_{RRM}$ 150°C mA
10ETF02FP	200	300	2
10ETF04FP	400	500	
10ETF06FP	600	700	

## Absolute Maximum Ratings

Parameters	10ETF..FP	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	10	A	@ $T_c = 98^\circ\text{C}$ , 180° conduction half sine wave
$I_{FSM}$ Max. Peak One Cycle Non-Repetitive Surge Current	150	A	10ms Sine pulse, rated $V_{RRM}$ applied
	160		10ms Sine pulse, no voltage reapplied
$I^2t$ Max. $I^2t$ for fusing	112.5	$A^2s$	10ms Sine pulse, rated $V_{RRM}$ applied
	160		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	1600	$A^2\sqrt{s}$	$t = 0.1$ to 10ms, no voltage reapplied

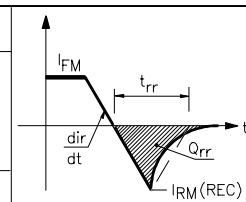
## Electrical Specifications

Parameters	10ETF..FP	Units	Conditions
$V_{FM}$ Max. Forward Voltage Drop	1.2	V	@ 10A, $T_j = 25^\circ\text{C}$
$r_t$ Forward slope resistance	23.5	$m\Omega$	$T_j = 150^\circ\text{C}$
$V_{F(TO)}$ Threshold voltage	0.85	V	
$I_{RM}$ Max. Reverse Leakage Current	0.1	mA	$T_j = 25^\circ\text{C}$
	3.0		$T_j = 150^\circ\text{C}$

$V_R = \text{rated } V_{RRM}$

## Recovery Characteristics

Parameters	10ETF..FP	Units	Conditions
$t_{rr}$ Reverse Recovery Time	145	ns	$I_F @ 10\text{Apk}$
$I_{rr}$ Reverse Recovery Current	2.75	A	@ 25A/ $\mu\text{s}$
$Q_{rr}$ Reverse Recovery Charge	0.32	$\mu\text{C}$	@ 25°C
S Snap Factor	0.6		



Thermal-Mechanical Specifications

Parameters	10ETF..FP	Units	Conditions
T <sub>J</sub> Max. Junction Temperature Range	-40 to 150	°C	
T <sub>stg</sub> Max. Storage Temperature Range	-40 to 150	°C	
R <sub>thJC</sub> Max. Thermal Resistance Junction to Case	2.5	°C/W	DC operation
R <sub>thJA</sub> Max. Thermal Resistance Junction to Ambient	62	°C/W	
R <sub>thCS</sub> Typical Thermal Resistance, Case to Heatsink	0.5	°C/W	Mounting surface, smooth and greased
wt Approximate Weight	2 (0.07)	g (oz.)	
T Mounting Torque	Min.	6 (5)	Kg-cm (lbf-in)
	Max.	12 (10)	
Case Style	TO-220ACFULLPAK		(94/V0)

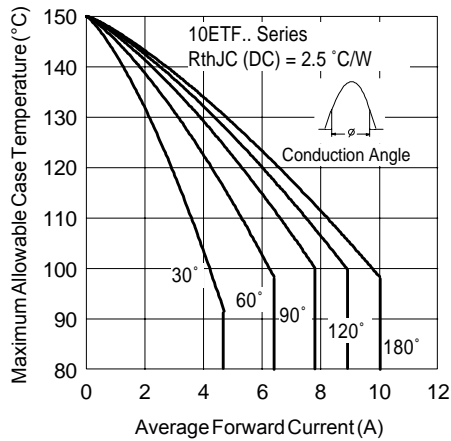


Fig. 1 - Current Rating Characteristics

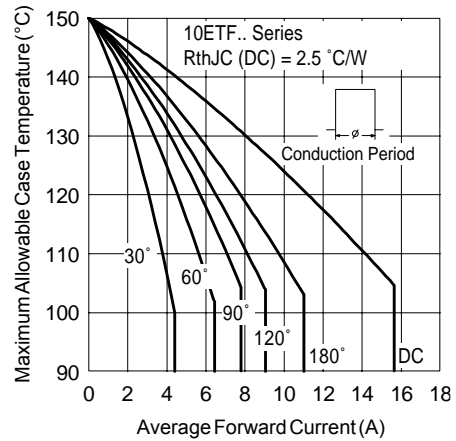


Fig. 2 - Current Rating Characteristics

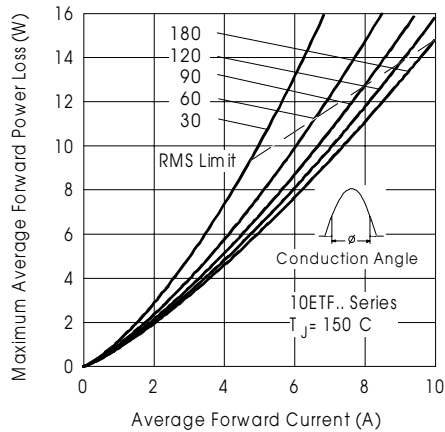


Fig. 3 - Forward Power Loss Characteristics

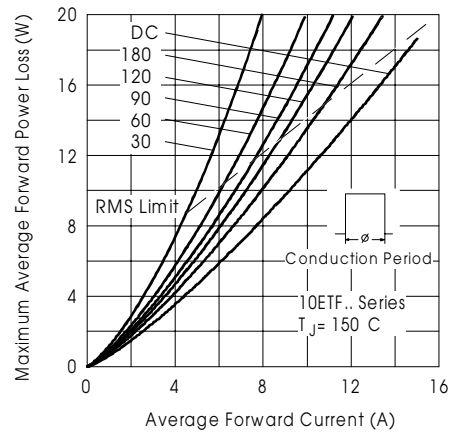


Fig. 4 - Forward Power Loss Characteristics

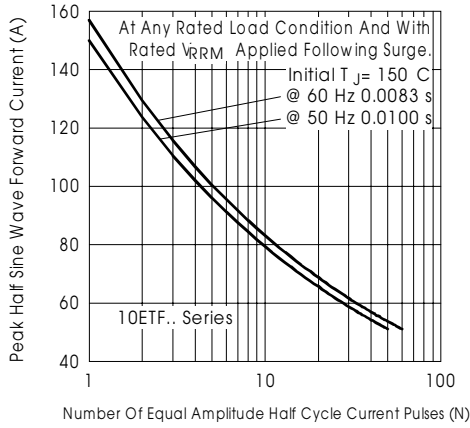


Fig. 5 - Maximum Non-Repetitive Surge Current

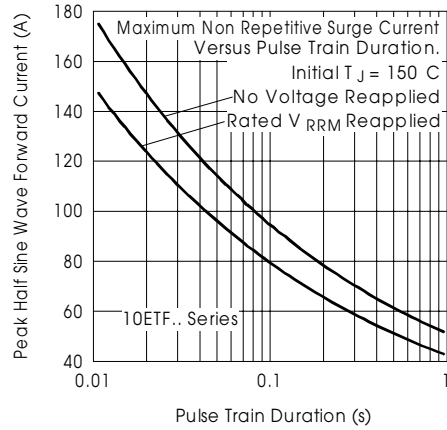


Fig. 6 - Maximum Non-Repetitive Surge Current

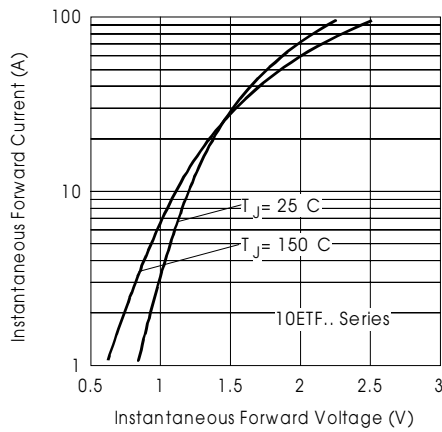


Fig. 7 - Forward Voltage Drop Characteristics

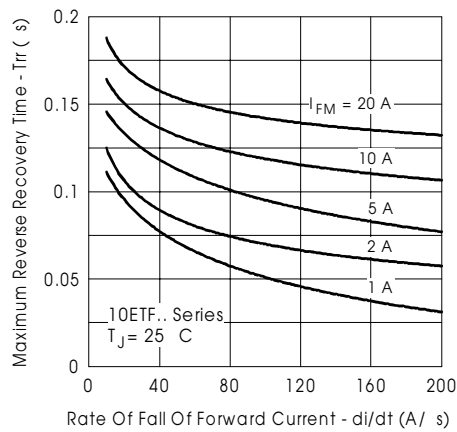


Fig. 8 - Recovery Time Characteristics,  $T_J = 25^\circ\text{C}$

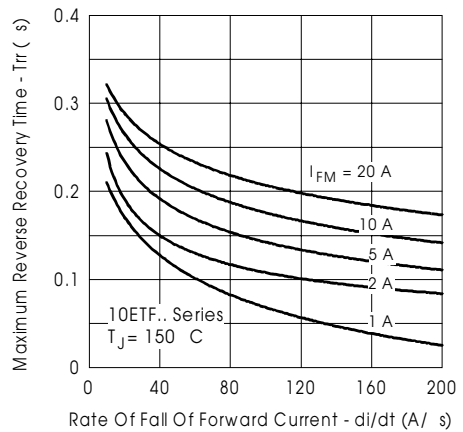


Fig. 9 - Recovery Time Characteristics,  $T_J = 150^\circ\text{C}$

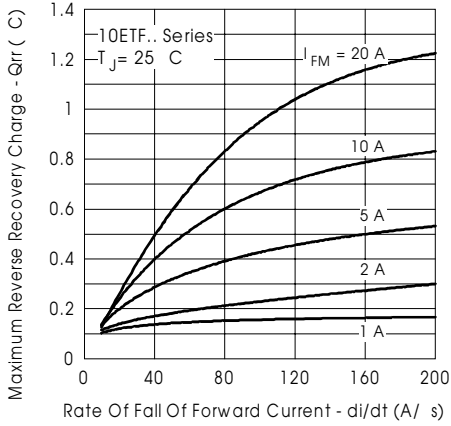


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25^\circ\text{C}$

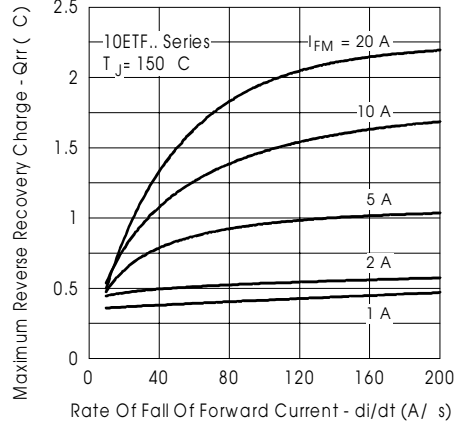


Fig. 11 - Recovery Charge Characteristics,  $T_J = 150^\circ\text{C}$

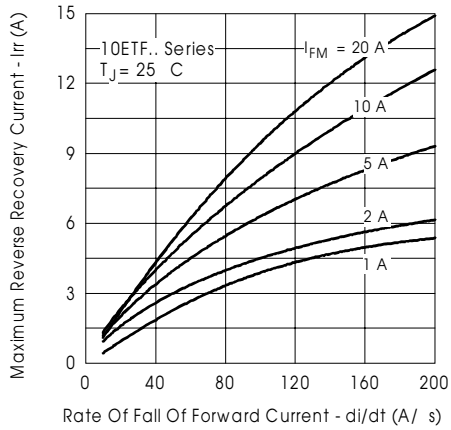


Fig. 12 - Recovery Current Characteristics,  $T_J = 25^\circ\text{C}$

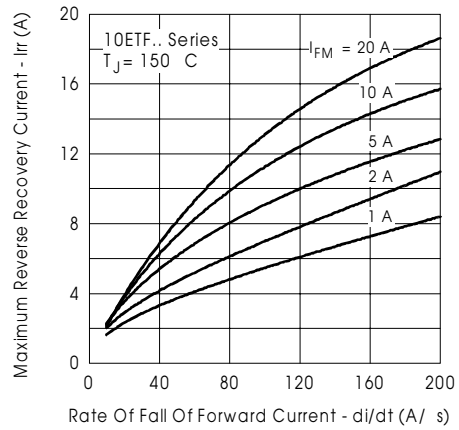


Fig. 13 - Recovery Current Characteristics,  $T_J = 150^\circ\text{C}$

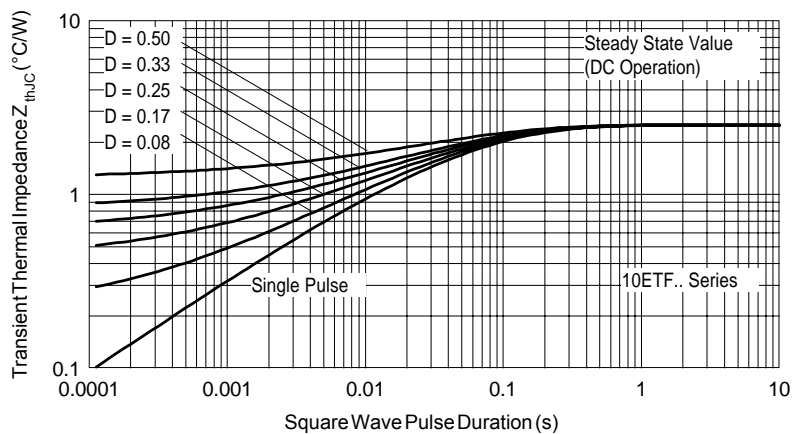


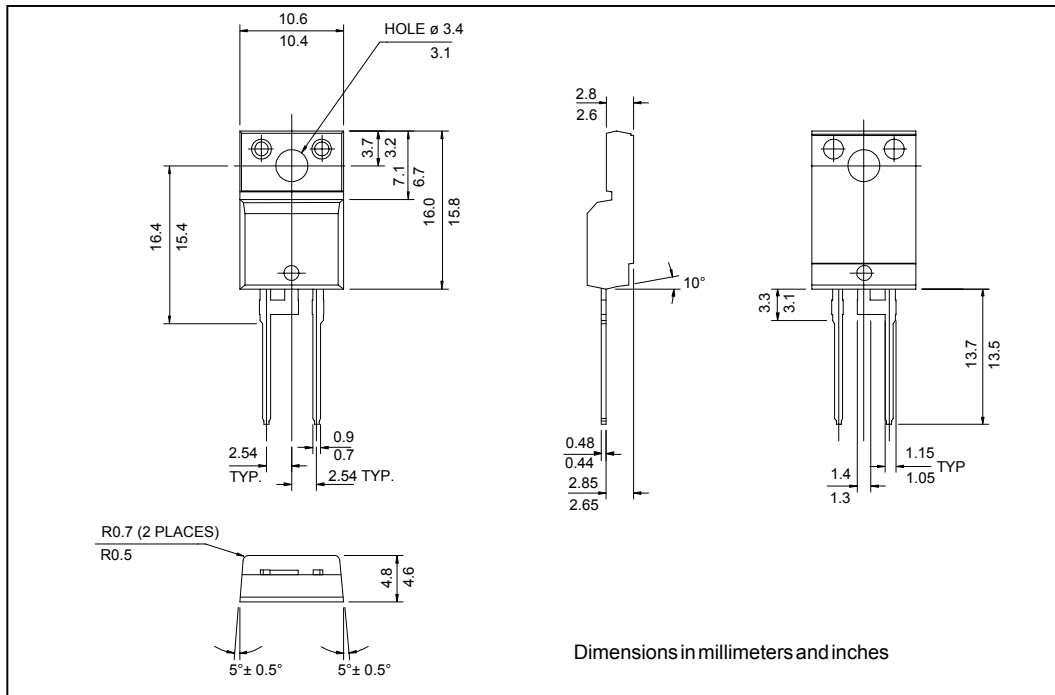
Fig. 14 - Thermal Impedance  $Z_{thjC}$  Characteristics

# 10ETF..FP QUIETIR Series

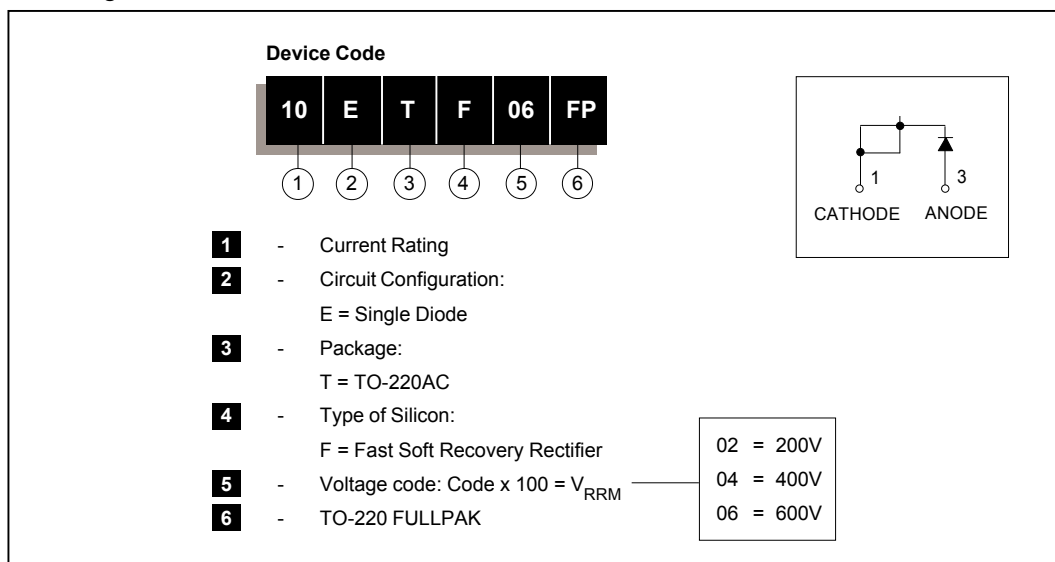
Bulletin I2163 04/02

International  
**IR** Rectifier

## Outline Table



## Ordering Information Table



Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

International  
**IOR** Rectifier

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